

# Simulation of a fast-ion conducting glass

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# Acknowledgements

- Maria Mitkova, Michael Kozicki  
(Programmable metallization cell device)
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- ££\$\$: U. S. NSF, Axon Technologies Corp



# Roadmap



- Silver-doped chalcogenide glass materials
- Application as a computer memory device
- Scientific Puzzles
- Our modeling (a work in progress!)
- Results and prospects

# Solid electrolytes

- High ionic conductivity, low electronic conductivity “solid electrolyte” or fast ion conductor.
- Usually, not always, cation conduction.
- Best conductivity  $\text{Li}^+$  (smallest) or  $\text{Ag}^+$  (most deformable)
- Applications: batteries, chemical sensors, supercapacitors and fuel cells...
- Basic process is thermally activated hopping

# Glassy solid electrolytes

- Often have glasses with *higher* ionic conductivity than crystal (eg. : Lithium Borate:  $\text{Li}_2\text{B}_4\text{O}_7$ )
- Conduction is isotropic
- No grain boundaries
- Continuously variable compositions possible

# Ag-doped chalcogenide glasses

- Silver doped chalcogenide glasses are solid electrolytes.
- Interesting photoresponse:
  - **Photodissolution** (light 'dissolves' surface Ag film into bulk)
  - **Photoexsolution** (light 'extracts' Ag from bulk to surface)

# Photo-induced surface deposition

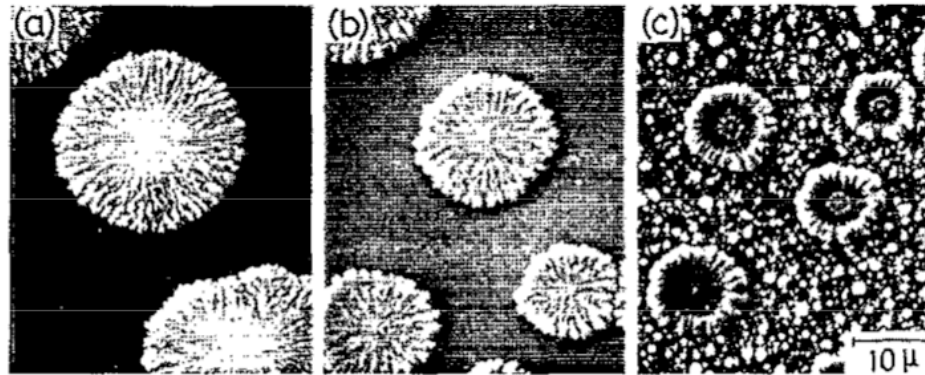
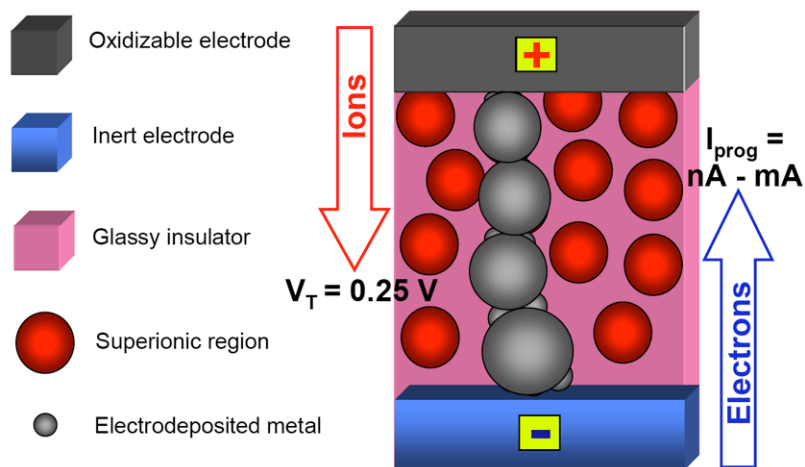
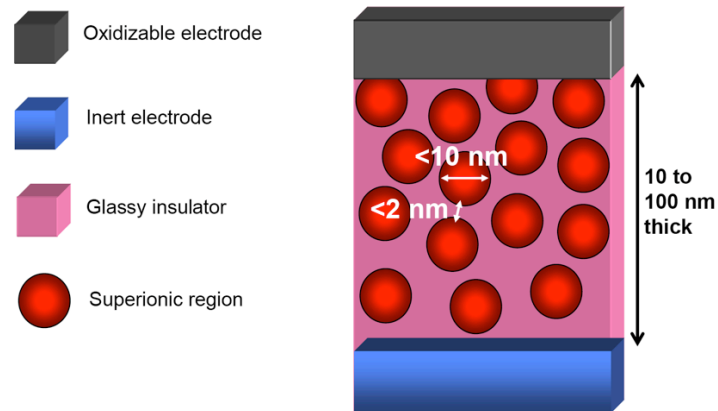


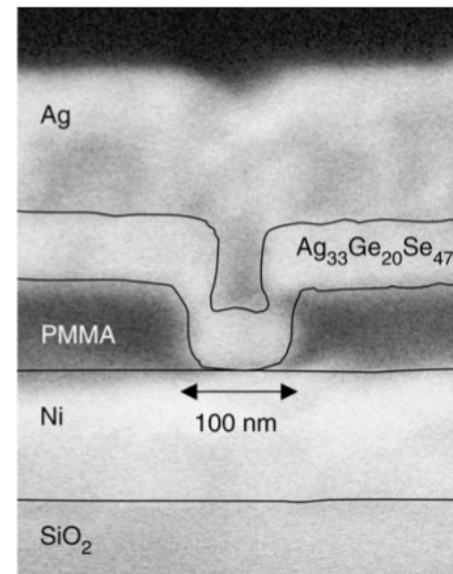
FIG. 3. SEM photographs of photodeposited Ag particles on  $\text{Ag}_{45}\text{As}_{15}\text{S}_{40}$  ( $x=45$ ) sample. The illuminations with lights of (a) 80, (b) 200, and (c) 530  $\text{mW}/\text{cm}^2$  were provided for 15 min at 21 °C.

T. Kawaguchi and S. Maruno JAP **77** 628 (1995)  
(Arsenic sulfide-based glass)  
T. Kawaguchi, S. Maruno and S. R. Elliott  
JAP **79** 9096 (1996) (S, Se-based glasses)

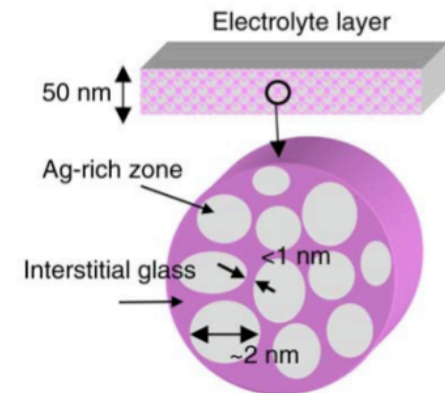
# Programmable Metallization Cell (PMC)



*M.N. Kozicki et al. / Superlattices and Microstructures 34 (2003) 459–465*



(a)



(b)

SEM image of device

PMC is nanostructured:  $\text{Ag}_2\text{Se}$  xtals in Ge-rich glass phase. Ag-rich crystallites ca. 2-7nm

Figures courtesy of M. N. Kozicki, M. Mitkova, ASU



# PMC

- A promising technology:
  - Low voltages needed:  $\sim 200 \text{ mV}$
  - Low power consumption
  - Fast: under  $20 \text{ ns}$  switch times
  - Good for at least  $10^{12}$  cycles

See: [www.axontc.com](http://www.axontc.com)

# Puzzles

- What is the structure of the bulk glass?
- Where does the Ag “sit”; and what is the nature of these traps?
- Why is the Ag so mobile?
- What is the mechanism of photo-induced surface deposition?

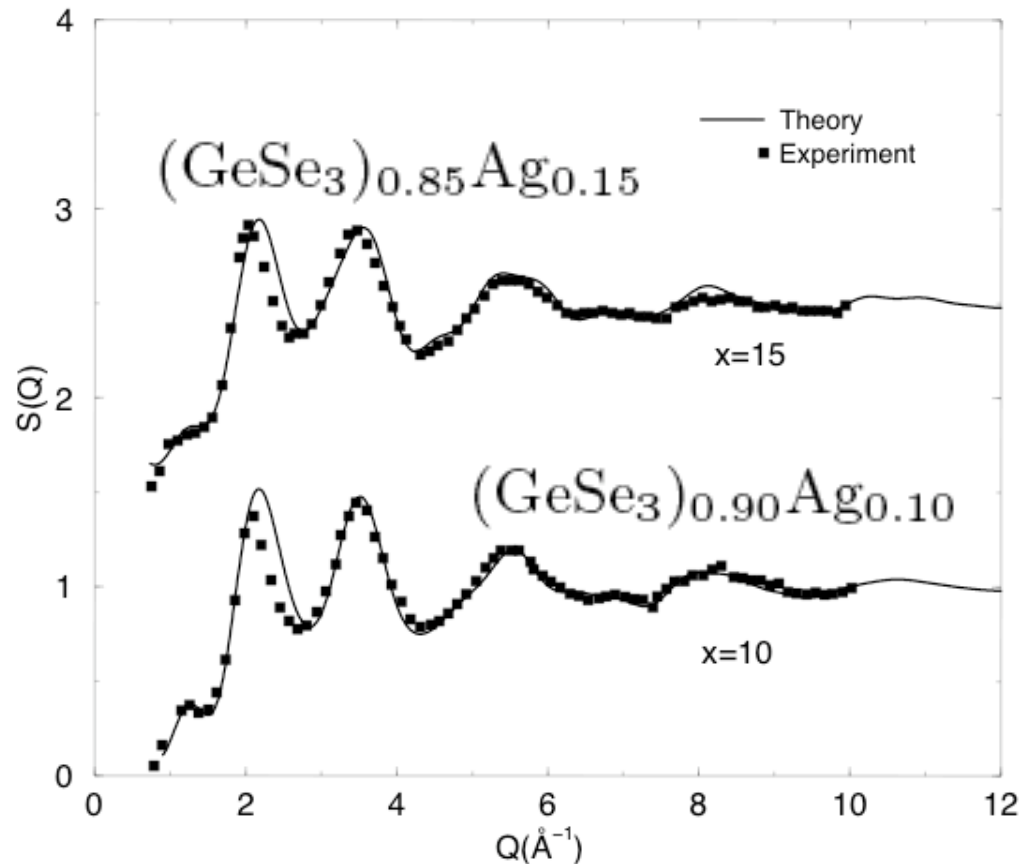
# Approach

- We use *ab initio* MD to model:  
 $a\text{-(GeSe}_3\text{)}_{.9}\text{Ag}_{.1}$  and  $a\text{-(GeSe}_3\text{)}_{.85}\text{Ag}_{.15}$
- Hamiltonians: FIREBALL2000 (local orbital LDA), VASP (plane wave LDA)
- Models made by conventional melt quenching (equilibrate liquid, quench over 5ps, anneal)

# Limitations

- Tiny models ( $\sim 250$  atoms)
- Short times ( $< 100$  ps)
- Homogeneous systems only: not picking up phase separation effects, which may be relevant for PMC.
- No electrochemistry yet.

# GeSe:Ag Models



Neutron total  
structure factors.

*Experiment:*

A. Piarristeguy, J.  
Non-Cryst. Sol. **332**,  
1 (2003).

# What does it mean?

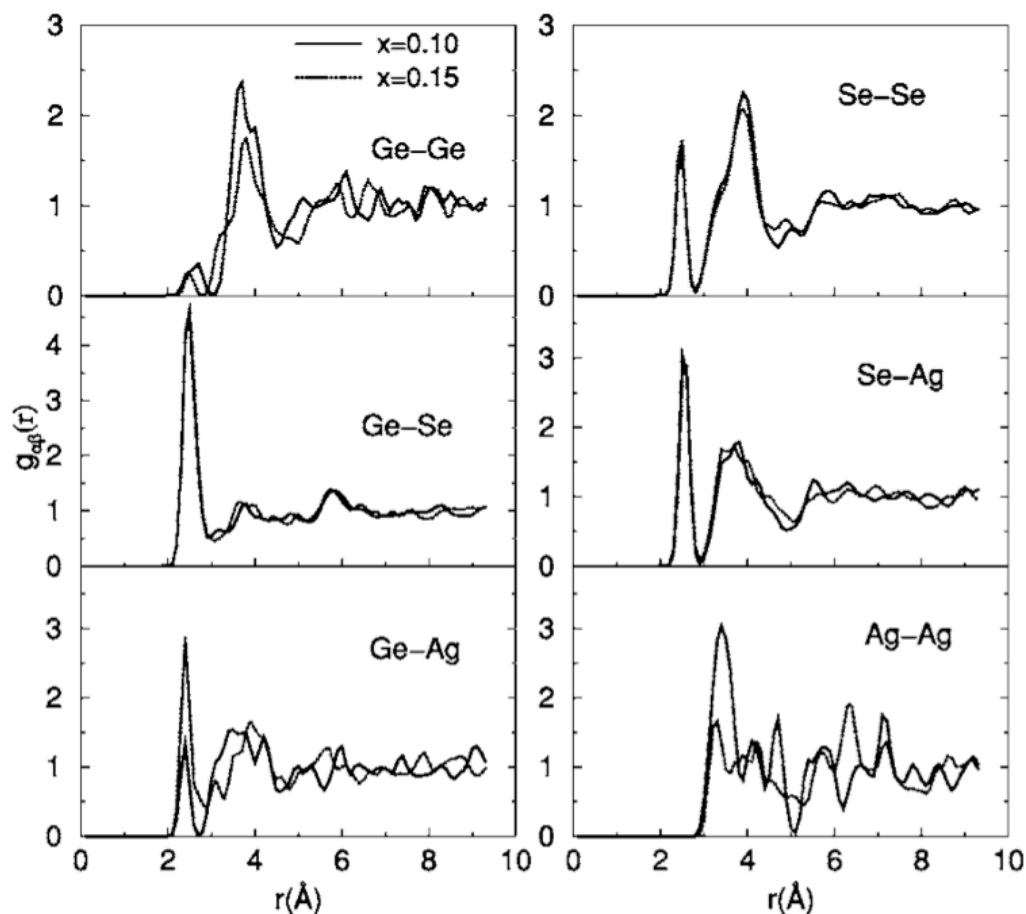
- Analysis of partials shows that first peak (near  $1.1\text{\AA}^{-1}$ ) is mostly due to Ge-Ge and Ag-Ag correlations. The peak becomes prominent with *increased* Ge and *decreased* Ag content.
- Continuous wavelet transform methods (Harrop, Taraskin, Elliott *et al.*) suggest that peaks near  $k\sim 2.0\text{\AA}^{-1}$ ,  $3.5\text{\AA}^{-1}$  involve extended spatial correlations (up to  $15\text{-}20\text{\AA}$ )

# Network Topology and Chemical Order

- Silver is **mostly two-fold**: 100% for  $x=0.1$  and 86% for  $x=0.15$  (remainder three-fold)

	Ge <sub>4</sub>	Ge <sub>3</sub>	Se <sub>2</sub>	Se <sub>3</sub>	Se <sub>1</sub>	Ag <sub>2</sub>	Ag <sub>3</sub>
$x=0.10$	35 (65%)	17 (31.5%)	86 (53.1%)	56 (33.9%)	17 (11.8%)	24 (100%)	—
$x=0.15$	34 (66.7%)	13 (25.5%)	85 (55.6%)	57 (37.2%)	11 (7.2%)	31 (86.1%)	4 (11.1%)
	Ge-Se	Se-Se	Ag-Se	Ag-Ge			
$x=0.10$	64%	21%	13%	1.5%			
$x=0.15$	57.1%	19.2%	18.2%	5.2%			

# Partial RDFs

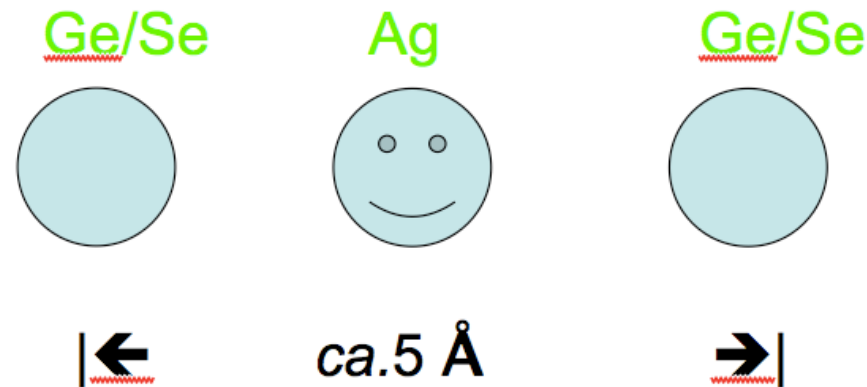


← **Ag-Ag** no clear correlations “random” for these  $x$ . (*nb.* limited statistics)



# Traps: I

- Ag sits midway between host atoms separated by about 5Å. Call this a *trapping center* (TC).



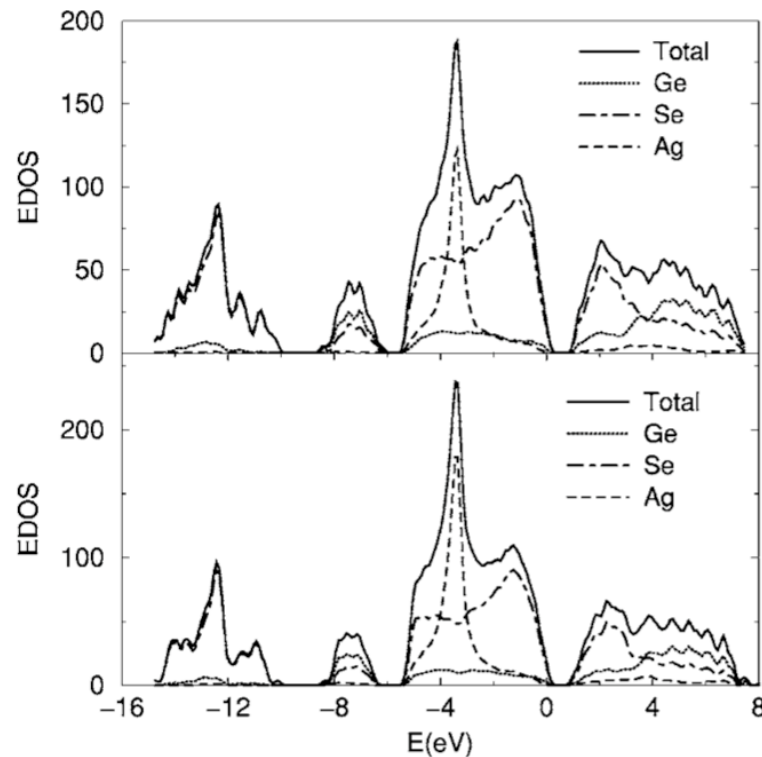
- This emerged for FIREBALL and VASP from melt-quench models and for unbonded Ag introduced in the network: Ag ‘finds its way’ to the same form of TC.

# Traps: II

- The TCs are distributed in the glass. Silver sits at isolated TC (32%) or in region with higher density of TC (68%) available.
- The Ag sub-system is a sort of “glass within a glass”. How does ‘melting’ proceed for trap system?

# Electronic Density of States

SILVER TRANSPORT IN  $\text{Ge}_x\text{Se}_{1-x}:\text{Ag}$  MATERIALS:...



Top valence band:  
Ge and Se p-states,  
Ag 4d. Band edges  
mostly due to Se 4p  
lone pairs

Tafen, Mitkova, DD PRB **72** 054206 (2005)

FIG. 5. Electronic density of states and species projected electronic density of states for Se, Ge, and Ag for  $(\text{GeSe}_3)_{0.90}\text{Ag}_{0.10}$  (top panel) and  $(\text{GeSe}_3)_{0.85}\text{Ag}_{0.15}$  (bottom panel) glasses.

# Electrons: II

- With VASP, we find electronic deep donor level for non-bonded Ag ( $\sim 0.2\text{eV}$  below LUMO).
- In a simple picture of light-solid interactions, photodiffusion might be associated with (light-induced) occupation changes in these levels.

# Ag dynamics ( $x=0.15$ , $T=1000K$ )

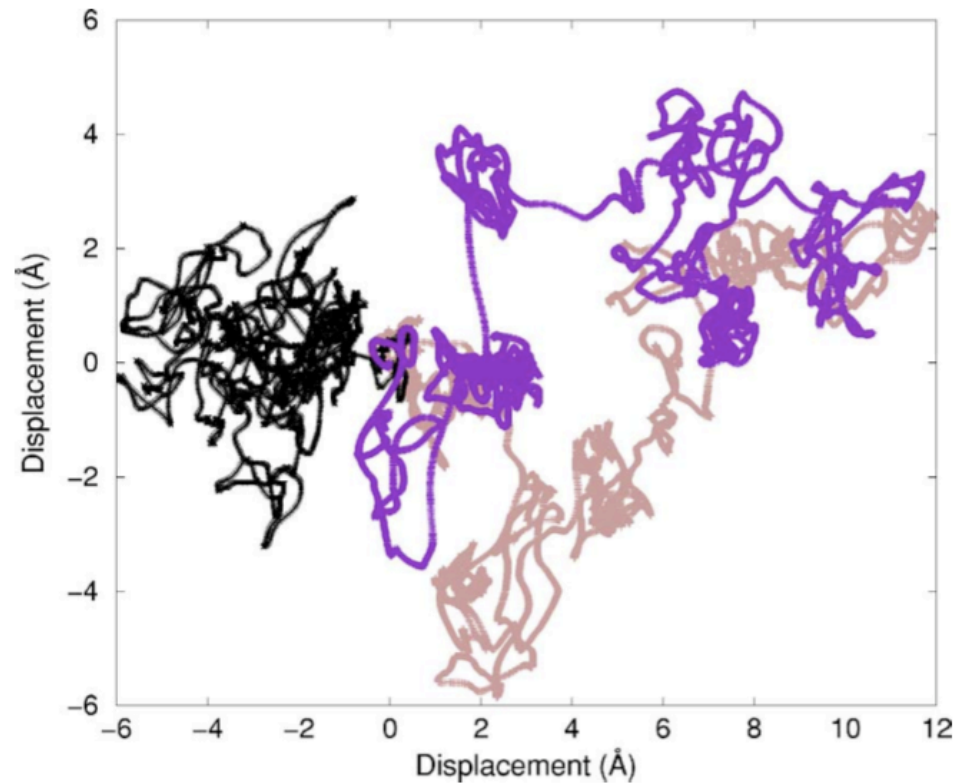
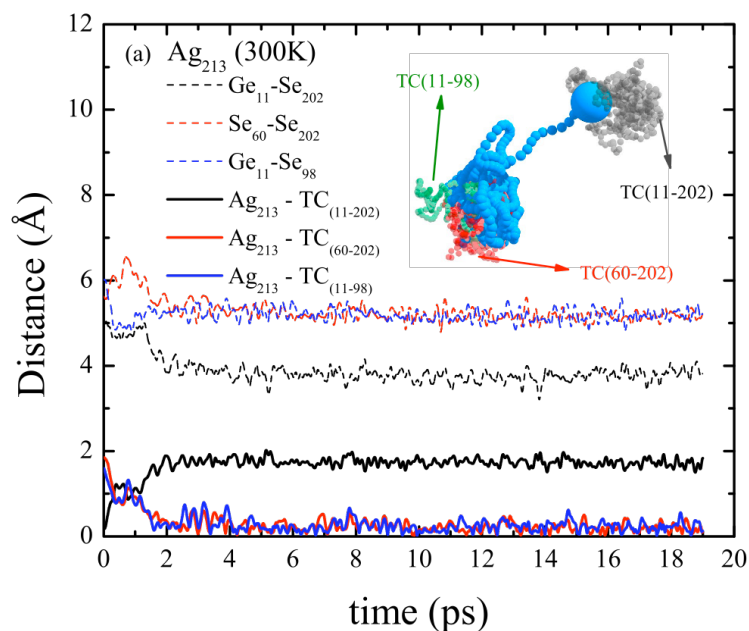


FIG. 8. (Color online) Trajectories of the most (indigo and brown) and least (black) mobile Ag atoms in  $(\text{GeSe}_3)_{0.85}\text{Ag}_{0.15}$  glass ( $T=1000$  K).

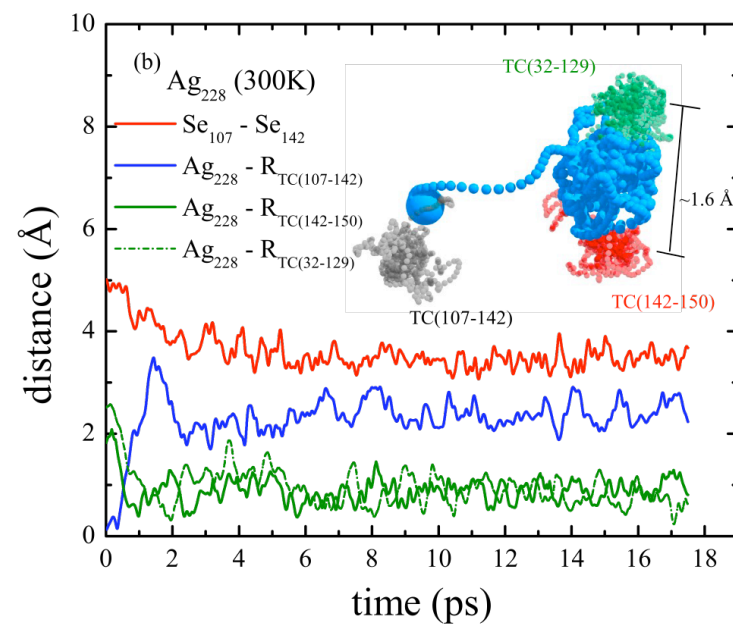
# Ag trapping/diffusion

- Average trapping time: *ca.* 2-3 ps (1000K)
- From Einstein relation,  $D \sim 1-2 \times 10^{-5} \text{ cm}^2/\text{s}$  at  $T=1000\text{K}$  for both glasses. Short simulations: *caveat emptor.*
- Extrapolating to 300K gives  $D$  within in factor of  $\sim 10$  of experiment (Urena *et al.*, 2005)

# Examples of Hopping



Isolated trap “big hop”



Multiple traps

There is rapid hopping among the adjoining TCs for volumes with more TCs.

# Ag Dynamics

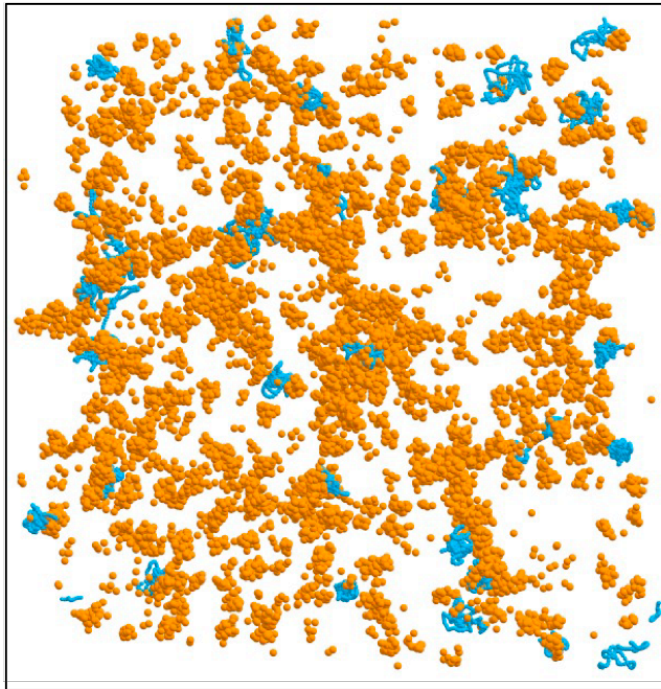
- “Supertraps” exist. Hopping is faster and shorter-ranged in parts of cell with higher trap density.
- “Long” hops from isolated traps.

Reminiscent of “diffusive” and “non-diffusive” processes of **Middleton and Wales** (PRB **64** 024205 2001).

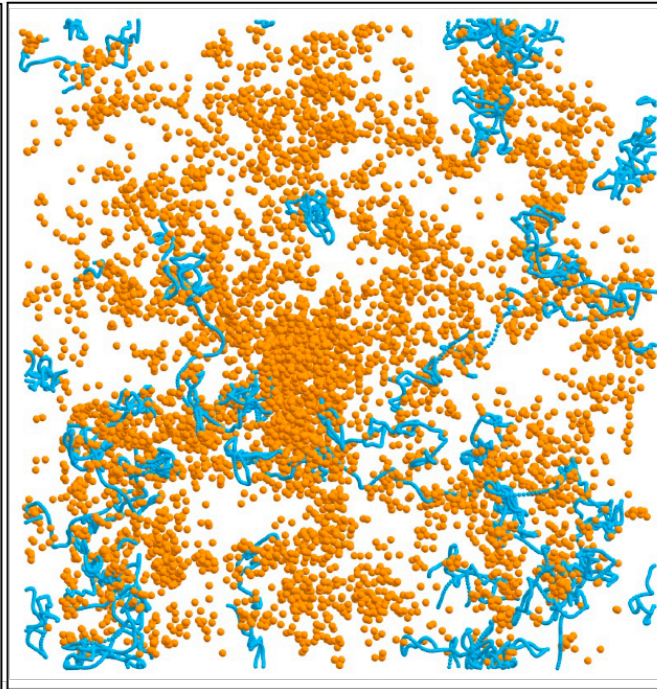


# Trap and Ag dynamics

(a) 300K



(b) 700K



Orange: traps  
Blue: Ag

# Silver dynamics

- At 300K the Ag and TCs are uniformly distributed in cell.
- At 700K the TC-network becomes more diffuse, and the Ag-network “melts” heterogeneously: large hops from isolated TCs, small, rapid hops from overlapping TCs.

# Some inferences

- There are *trapping centers*. This is a direct observation of the **Scher-Lax-Phillips**<sup>1</sup> traps. Trap model is successful to explain relaxation data.
- Traps have a dynamic character: fill more of space at higher T.
- We need better statistics. Absorption and emission rates of cages, temperature dependence etc. In progress.
- Local basis (FIREBALL) and plane wave (VASP) produce very similar results.

<sup>1</sup>**J. C. Phillips**, Rep. Prog. Phys **59** 1133 (1996).

# Whats next?

- Surface structure
- Phase separation, interfaces
- Photoresponse
- Electrochemistry and filament growth